Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material: Metal **Overall Length:** 0.750 inches **Mounting Facility Quantity:** 1 Internal Configuration: Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.734 inches and 0.750 inches **Thread Size:** 0.312 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 breakover voltage, dc **Current Rating Per Characteristic:** 54.00 amperes source cutoff current of standard range Maximum Operating Tempurature Per Measurement Point: 125.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 2 tab, solder lug Shelf Life: N/a Unit Of Measure: ---**Demilitarization:** No Fiig: A110a0